

# Uniform tiling with electrical resistors

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Electric resistances between two arbitrary nodes on any infinite lattice structure of resistor networks that is a periodic tiling of the space is obtained. Our general approach is based on the lattice Green's function of the Laplacian matrix associated with the network. We present several and non-trivial examples to show how efficient our method is. Deriving explicit resistance formulas it is shown that the Kagomé, the diced and the decorated lattice can be mapped to the triangular and square lattice of resistors. Our work can be extended to random walk problem or electron dynamics in condensed matter physics.

## I. INTRODUCTION

In electric circuit theory one of the classic problems is to calculate the resistance between two arbitrary grid points on an infinite square lattice of identical resistors. This problem has been published by van der Pol and Bremmer [1]. In a special case, it is well known that the resistance between two adjacent grid points of an infinite square lattice is half of the resistance of a bond and an elegant and elementary solution of the problem is given by Aitchison [2]. Over many years numerous authors have studied this problem and its extension to triangular, honeycomb and hypercube lattices (for some relevant references see, eg, [3–5]).

The resistor network can systematically be treated by the Laplacian operator of the difference equations governed by the Ohm's and Kirchhoff's laws. Then the Green's function corresponding to the Laplacian operator can be related to the resistance between two arbitrary nodes on a resistor network. This idea has been applied by Kirkpatrick to study percolating networks of resistors [6]. Recently, it has been demonstrated that the application of the Green's function is very efficient to find the resistance for infinite resistor network as well [5]. The concept of Green's function is widely used in the literature. Economou's book [7] gives an excellent introduction to the Green's function. Katsura et. al. have a review of the lattice Green's function [8] and for more works on this topic, see references in Ref. [5]. From the equation for the Green's function one can, in principle, derive some so-called recurrence formulas for the resistances between arbitrary grid points of an infinite lattice (for square lattice of resistor network see Ref. [5]). The Green's function can also be a useful tool to study, eg, the capacitor networks [9] or the resistance in a perturbed lattice in which one of the bond is missing in the lattice [10]. The Green's function for anisotropic diamond lattice was discussed by Hijawwi [11] and the analytical properties of the Green's function in all dimensions was investigated by Guttmann [12].

The problem of the finite resistor network is equally interesting in circuit theory. Recently, Wu has developed a theory to calculate the resistance between arbitrary nodes for finite lattice of resistors [13], and Tzeng and Wu for impedance networks [14], The corner-to-corner resistance was evaluated exactly by Essam and Wu [15] and its asymptotic expansion was calculated by Izmailian and Huang [16].

Calculation of the resistance in electric circuit theory can also be relevant to many other problems, such as random walks [17, 18] and first-passage processes [19]. This connection is based on the fact that the difference equations for the electrical potentials on a lattice point of a resistor network is the same as that occur in the above mentioned problems. Thus the resistance problem can be regarded as a problem to solve the difference equations for an infinite network.

In this work we generalize the Green's function approach developed in Ref. [5] for a resistor network that is a uniform tiling of the  $d$  dimensional space with electrical resistors. In two dimensions, tiling is a collection of plane figures that fills the plane with no overlaps and no gaps. Generalization to other dimensions is also possible. Figure 1 shows an example for a uniform tiling with resistors. Here we derive an explicit

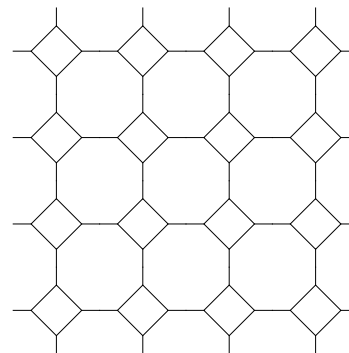


FIG. 1. An example for a lattice structure of infinite resistor networks discussed in this work. The lattice is a periodic tiling of the plane by squares and octagons. Here, all lines represent a resistor with resistance  $R$ .

expression for the resistance between two arbitrary nodes of any lattice structure which is a periodic tiling of the  $d$  dimensional space with electrical resistors. We present several examples for nontrivial resistor networks that, to our best knowledge, are not studied in the literature. Our Green's function method enables us to derive, for the first time, resistance formulas for Kagomé and diced lattice (see Secs. III C and III D), and for decorated lattice (see Sec. III E) in terms of the resistances on the well studied triangular and square lattice, respectively. Our general method is not restricted to lattice structure made from identical resistors as it is demonstrated in a sim-

ple, one dimensional example. Moreover, our method can be extended to a uniform tiling of a surface of toroid or cylinder. The theory of perturbed lattice developed in Ref. [10] can easily be extended to such resistor networks that we discuss in this work.

In condensed matter physics, often the tight binding model (see, eg, [7, 20–25]) is a very good approximation for calculating the electronic band structure or transport properties of a crystalline matter, like the recently discovered graphene [26, 27]. In such investigation the knowledge of the Green's function corresponding to the Schrödinger equation is essential. Our results may be used to calculate the wave functions at the lattice points for complicated lattice structures.

The text is organized as follows. In Sec. II we outlined the general formalism to calculate the two point resistance on an arbitrary periodic lattice. Several, non trivial examples are presented in Sec. III together with a few analytical results regarding the resistance between nearby lattice points. The conclusions are drawn in Sec. IV. In the Appendices we listed the resistance formulas that provide mapping of the Kagomé and diced lattice to the triangular lattice, and the decorated lattice to square lattice.

## II. GENERAL FORMALISM

Here we derive a general integral expression for the resistance between two arbitrary lattice points in an infinite regular lattice of any resistor network.

First, we specify the  $d$ -dimensional regular lattice by its unit cell as it is common in solid state physics. The lattice point is given by  $\mathbf{r} = n_1\mathbf{a}_1 + n_2\mathbf{a}_2 + \dots + n_d\mathbf{a}_d$ , where  $\mathbf{a}_1, \mathbf{a}_2, \dots, \mathbf{a}_d$  are the unit cell vectors in the  $d$ -dimensional space and  $n_1, n_2, \dots, n_d$  are arbitrary integers. We assume that in each unit cell there are  $p$  number of lattice points labeled by  $\alpha = 1, 2, \dots, p$ . Now we denote any lattice point by  $\{\mathbf{r}, \alpha\}$ , where  $\mathbf{r}$  and  $\alpha$  specify the unit cell and the lattice point in the given unit cell, respectively. Figure 1 shows an example for the lattice structure of a resistor network. We assume that all lines represent a resistor with resistance  $R$  (although in the general formalism this have not been made use). Figure 2 shows one possible choice for the unit cell of the lattice shown in Fig. 1. There are four types of lattice points in each unit cell denoted by  $\alpha = 1, 2, 3, 4$  in Fig. 2.

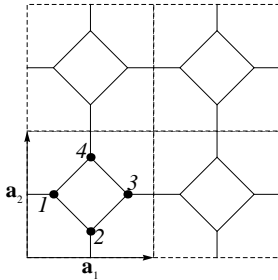


FIG. 2. The unit cell (dashed lines) with unit vector  $\mathbf{a}_1$  and  $\mathbf{a}_2$  of the lattice shown in Fig. 1. There are four lattice points in each unit cell labeled by  $\alpha = 1, 2, 3, 4$ .

Denote the electric potential at the lattice point  $\{\mathbf{r}, \alpha\}$  by  $V_\alpha(\mathbf{r})$  and the net current flowing into the network at the lattice point  $\{\mathbf{r}, \alpha\}$  by  $I_\alpha(\mathbf{r})$  (as one can see below it is convenient to treat the problem by assuming that the current enter at  $\{\mathbf{r}, \alpha\}$  from a source outside the lattice). Owing to Ohm's and Kirchoff's laws the current  $I_\alpha(\mathbf{r})$  relates to the potential  $V_\alpha(\mathbf{r})$  by the following equations:

$$\sum_{\mathbf{r}', \beta} L_{\alpha\beta}(\mathbf{r} - \mathbf{r}') V_\beta(\mathbf{r}') = -I_\alpha(\mathbf{r}), \quad (1)$$

where  $L_{\alpha\beta}(\mathbf{r} - \mathbf{r}')$  is a  $p$  by  $p$  matrix called *connectivity matrix* or *Laplacian matrix*. For concrete examples see Sec. III. The minus sign has been introduced only for conveniences. In fact, if there is only one lattice point in each unit cell, ie,  $p = 1$ , then  $L_{\alpha\beta}(\mathbf{r} - \mathbf{r}')$  is the lattice Laplacian corresponding to the finite-difference representation of the Laplace operator used in the literature (see, eg, Refs. 5 and 28). From the translation symmetry of the lattice structure it follows that the Laplacian matrix depends only on the difference  $\mathbf{r} - \mathbf{r}'$ . Equation (1) can be written in a more compact form using matrix notation:  $\sum_{\mathbf{r}'} \mathbf{L}(\mathbf{r} - \mathbf{r}') \mathbf{V}(\mathbf{r}') = -\mathbf{I}(\mathbf{r})$ . Owing to the nature of the connectivity between lattice points the Laplacian matrix satisfies the following relation:  $\mathbf{L}(\mathbf{r}) = \mathbf{L}^T(-\mathbf{r})$ , where T denotes the transpose of a matrix.

We now take periodic boundary conditions and consider a lattice with  $N_1, N_2, \dots, N_d$  unit cells along each unit cell vector  $\mathbf{a}_1, \mathbf{a}_2, \dots, \mathbf{a}_d$ . Thus the total number of unit cells in the  $d$  dimensional lattice is  $N = \prod_{i=1}^d N_i$  and the total number of lattice points is  $Np$ . Now, it is useful to introduce the reciprocal lattice. Owing to the periodic boundary conditions, the wave vector  $\mathbf{k}$  in the reciprocal lattice is limited to the first Brillouin zone (BZ) and is given by

$$\mathbf{k} = \frac{m_1}{N_1} \mathbf{b}_1 + \frac{m_2}{N_2} \mathbf{b}_2 + \dots + \frac{m_d}{N_d} \mathbf{b}_d, \quad (2)$$

where  $m_1, m_2, \dots, m_d$  are integers such that  $-N_i/2 \leq m_i \leq N_i/2$  for  $i = 1, 2, \dots, d$ , and  $\mathbf{b}_j$  are the reciprocal lattice vectors defined by  $\mathbf{a}_i \mathbf{b}_j = 2\pi \delta_{ij}$ ,  $i, j = 1, 2, \dots, d$ . Here we assumed that each  $N_i$  is an even integer, which will be irrelevant in the limit  $N_i \rightarrow \infty$ . The mathematical description of the crystal lattice and the concept of the Brillouin zone can be found in many books on solid state physics[20–25].

We take the discrete Fourier transform of the current  $\mathbf{I}(\mathbf{r})$ :

$$\mathbf{I}(\mathbf{k}) = \sum_{\mathbf{r}} \mathbf{I}(\mathbf{r}) e^{-i\mathbf{k}\mathbf{r}}, \quad (3a)$$

and an analogous expression is valid for the potential  $V_\alpha(\mathbf{k})$ . Then the inverse Fourier transforms are given by

$$\mathbf{I}(\mathbf{r}) = \frac{1}{N} \sum_{\mathbf{k} \in \text{BZ}} \mathbf{I}(\mathbf{k}) e^{i\mathbf{k}\mathbf{r}}, \quad (3b)$$

and the same is valid for the potential  $V_\alpha(\mathbf{r})$ . This expression can easily be proved using the well-known relation  $\sum_{\mathbf{r}} e^{i\mathbf{r}(\mathbf{k}-\mathbf{k}')} = N \delta_{\mathbf{k}, \mathbf{k}'}$  [20–25].

Using the Fourier transform of the current and the potential distributions Eq. (1) can be rewritten as

$$\mathbf{L}(\mathbf{k}) \mathbf{V}(\mathbf{k}) = -\mathbf{I}(\mathbf{k}), \quad (4a)$$

where

$$\mathbf{L}(\mathbf{k}) = \sum_{\mathbf{r}} \mathbf{L}(\mathbf{r}) e^{-i\mathbf{k}\mathbf{r}}. \quad (4b)$$

Since  $\mathbf{L}(\mathbf{r}) = \mathbf{L}^T(-\mathbf{r})$  it is obvious that  $\mathbf{L}(\mathbf{k})$  is a Hermitian matrix, ie,  $\mathbf{L}(\mathbf{k}) = \mathbf{L}^+(\mathbf{k})$ , where  $+$  denotes the conjugate transpose of a matrix.

For a given  $\mathbf{I}(\mathbf{k})$  the Fourier transform  $\mathbf{V}(\mathbf{k})$  of the potential distribution can easily be found from (4a):

$$\mathbf{V}(\mathbf{k}) = \mathbf{G}(\mathbf{k}) \mathbf{I}(\mathbf{k}), \quad (5a)$$

where the lattice *Green's function*  $\mathbf{G}(\mathbf{k})$  (in  $\mathbf{k}$ -space) is given by

$$\mathbf{G}(\mathbf{k}) = -\mathbf{L}^{-1}(\mathbf{k}). \quad (5b)$$

Since  $\mathbf{L}(\mathbf{k})$  is a Hermitian matrix, the Green's function  $\mathbf{G}(\mathbf{k})$  is also a Hermitian matrix. If there is only one lattice point in each unit cell, ie,  $p = 1$ , the lattice Green's function  $\mathbf{G}(\mathbf{k})$  is a one by one matrix and it is the lattice Green's function of the finite-difference representation of the Laplace operator used in the literature (see, eg, Ref. 5).

To measure the resistance between lattice points  $\{\mathbf{r}_1, \alpha_1\}$  and  $\{\mathbf{r}_2, \alpha_2\}$ , we assume that a current  $I$  enters at lattice point  $\{\mathbf{r}_1, \alpha_1\}$  and exits at lattice point  $\{\mathbf{r}_2, \alpha_2\}$ , and at any other lattice points the currents are zero. Therefore, the current distribution in this case can be written as

$$I_\nu(\mathbf{r}) = I(\delta_{\nu, \alpha_1} \delta_{\mathbf{r}, \mathbf{r}_1} - \delta_{\nu, \alpha_2} \delta_{\mathbf{r}, \mathbf{r}_2}), \quad (6a)$$

and its Fourier transform becomes

$$I_\nu(\mathbf{k}) = \sum_{\mathbf{r}} I_\nu(\mathbf{r}) e^{-i\mathbf{k}\mathbf{r}} = I(\delta_{\nu, \alpha_1} e^{-i\mathbf{k}\mathbf{r}_1} - \delta_{\nu, \alpha_2} e^{-i\mathbf{k}\mathbf{r}_2}). \quad (6b)$$

Using Eqs. (6b) and (5a) we find

$$\begin{aligned} V_\mu(\mathbf{k}) &= \sum_{\nu} G_{\mu\nu} I_\nu(\mathbf{k}) \\ &= I [G_{\mu\alpha_1}(\mathbf{k}) e^{-i\mathbf{k}\mathbf{r}_1} - G_{\mu\alpha_2}(\mathbf{k}) e^{-i\mathbf{k}\mathbf{r}_2}], \end{aligned} \quad (7a)$$

and the potential distribution in  $\mathbf{r}$ -space becomes

$$\begin{aligned} V_\mu(\mathbf{r}) &= \frac{1}{N} \sum_{\mathbf{k} \in \text{BZ}} V_\mu(\mathbf{k}) e^{i\mathbf{k}\mathbf{r}} \\ &= \frac{I}{N} \sum_{\mathbf{k} \in \text{BZ}} [G_{\mu\alpha_1}(\mathbf{k}) e^{i\mathbf{k}(\mathbf{r}-\mathbf{r}_1)} - G_{\mu\alpha_2}(\mathbf{k}) e^{i\mathbf{k}(\mathbf{r}-\mathbf{r}_2)}]. \end{aligned} \quad (7b)$$

Now the resistance between lattice points  $\{\mathbf{r}_1, \alpha_1\}$  and  $\{\mathbf{r}_2, \alpha_2\}$  is given by

$$R_{\alpha_1\alpha_2}(\mathbf{r}_1, \mathbf{r}_2) = \frac{V_{\alpha_1}(\mathbf{r}_1) - V_{\alpha_2}(\mathbf{r}_2)}{I}. \quad (8)$$

Then using Eq. (7b) we find

$$\begin{aligned} R_{\alpha_1\alpha_2}(\mathbf{r}_1, \mathbf{r}_2) &= \frac{1}{N} \sum_{\mathbf{k} \in \text{BZ}} [G_{\alpha_1\alpha_1}(\mathbf{k}) + G_{\alpha_2\alpha_2}(\mathbf{k}) \\ &\quad - G_{\alpha_1\alpha_2}(\mathbf{k}) e^{-i\mathbf{k}(\mathbf{r}_2-\mathbf{r}_1)} - G_{\alpha_2\alpha_1}(\mathbf{k}) e^{i\mathbf{k}(\mathbf{r}_2-\mathbf{r}_1)}]. \end{aligned} \quad (9)$$

If we take the limit  $N_i \rightarrow \infty$  for all  $i = 1, 2, \dots, d$  then the discrete summation over  $\mathbf{k}$  can be substituted by an integral [20–25]:

$$\frac{1}{N} \sum_{\mathbf{k} \in \text{BZ}} \rightarrow v_0 \int_{\mathbf{k} \in \text{BZ}} \frac{d^d \mathbf{k}}{(2\pi)^d}, \quad (10)$$

where  $v_0$  is the volume of the unit cell. Thus the resistance  $R_{\alpha_1\alpha_2}(\mathbf{r}_1, \mathbf{r}_2)$  becomes

$$\begin{aligned} R_{\alpha_1\alpha_2}(\mathbf{r}_1, \mathbf{r}_2) &= v_0 \int_{\mathbf{k} \in \text{BZ}} \frac{d^d \mathbf{k}}{(2\pi)^d} [G_{\alpha_1\alpha_1}(\mathbf{k}) + G_{\alpha_2\alpha_2}(\mathbf{k}) \\ &\quad - G_{\alpha_1\alpha_2}(\mathbf{k}) e^{-i\mathbf{k}(\mathbf{r}_2-\mathbf{r}_1)} - G_{\alpha_2\alpha_1}(\mathbf{k}) e^{i\mathbf{k}(\mathbf{r}_2-\mathbf{r}_1)}]. \end{aligned} \quad (11)$$

This is the central result of this work. Note that the resistance depends only on the difference  $\mathbf{r}_2 - \mathbf{r}_1$  which is the consequence of the translation symmetry of the resistor lattice. Since  $\mathbf{G}(\mathbf{k})$  is a Hermitian matrix, it is clear that the first two and the sum of the last two terms in the above expression are real, thus the resistance is real, as should be. Moreover, from Eq. (11) the following symmetry relation  $R_{\alpha_1\alpha_2}(\mathbf{r}_1, \mathbf{r}_2) = R_{\alpha_2\alpha_1}(\mathbf{r}_2, \mathbf{r}_1)$  is also obvious.

It is clear that deforming the lattice structure the resistance between two arbitrary lattice points does not change if the topology of the lattice structure is preserved. The same deformation was used by Atkinson and Steenwijk [4] for triangular lattice. Thus, one can always deform the lattice structure of any resistor network into a  $d$  dimensional hypercube in which all the unit cell vectors have the same magnitude and they are perpendicular to each other. This topologically equivalent  $d$  dimensional hypercube lattice is more suitable for evaluating in Eq. (11) the necessary integrals over the Brillouin zone since the Brillouin zone also becomes a  $d$  dimensional hypercube. Indeed, if we write  $\mathbf{r}_2 - \mathbf{r}_1$  in terms of the unit cell vectors:  $\mathbf{r}_2 - \mathbf{r}_1 = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 + \dots + n_d \mathbf{a}_d$  then the exponentials in Eq. (11) and the Green's function will depend on the variables  $x_1 = \mathbf{k}\mathbf{a}_1, x_2 = \mathbf{k}\mathbf{a}_2, \dots, x_d = \mathbf{k}\mathbf{a}_d$ , ie,

$$\mathbf{G}(x_1, \dots, x_d) = \mathbf{G}(\mathbf{k}\mathbf{a}_1 \rightarrow x_1, \dots, \mathbf{k}\mathbf{a}_d \rightarrow x_d). \quad (12)$$

Moreover, the integration variables  $\mathbf{k} = (k_1, k_2, \dots, k_d)$  in (11) can also be transformed to the variables  $x_1, x_2, \dots, x_d$  for which the limits of the integration are  $\pm\pi$ . The Jacobian corresponding to the transformations of variables cancels the volume  $v_0$  of the unit cell in (11). Thus, the general result (11) for the resistance can be rewritten into a  $d$  dimensional integral that is a more suitable form for explicit calculations:

$$\begin{aligned} R_{\alpha_1\alpha_2}(n_1, \dots, n_d) &= \int_{-\pi}^{\pi} \frac{dx_1}{2\pi} \dots \int_{-\pi}^{\pi} \frac{dx_d}{2\pi} \\ &\quad [G_{\alpha_1\alpha_1}(x_1, \dots, x_d) + G_{\alpha_2\alpha_2}(x_1, \dots, x_d) \\ &\quad - G_{\alpha_1\alpha_2}(x_1, \dots, x_d) e^{-i(n_1 x_1 + n_2 x_2 + \dots + n_d x_d)} \\ &\quad - G_{\alpha_2\alpha_1}(x_1, \dots, x_d) e^{i(n_1 x_1 + n_2 x_2 + \dots + n_d x_d)}]. \end{aligned} \quad (13)$$

For any infinite regular resistor network the above result is an integral representation of the resistance between arbitrary

lattice points and provides a practical way for determining the resistance in question.

### III. APPLICATIONS OF THE GENERAL FORMALISM

In this section we demonstrate how this result can be applied for different lattice structures. We present examples for one, two and three dimensional cases as well.

#### A. One dimensional resistor structure

Perhaps, the simplest periodic tiling is the one dimensional lattice structure in which each unit cell contains two non-equivalent resistors as shown in Fig. 3. This lattice structure

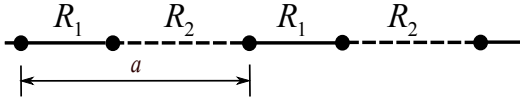


FIG. 3. A periodic tiling in one dimension with two resistors  $R_1$  and  $R_2$ . In this lattice each unit cell contains two non-equivalent lattice points labeled by  $\alpha = 1, 2$ , ie,  $p = 2$ . The length of the unit cell is  $a$ .

is also an example for the case in which the connectivity between lattice points in each unit cell are not necessary the same. As we mentioned before, our general formalism outlined above can be applied for such cases as well. Indeed, now there are two different resistances in the unit cell,  $R_1$  and  $R_2$ .

In one dimension we can characterize lattice points by  $\{r, \alpha\}$ , where  $r = ma$  and  $\alpha = 1, 2$  (here  $m$  is an integer). The Ohm's and Kirchoff's laws for the currents  $I_\alpha(r)$  at site  $\{r, \alpha\}$  (with  $\alpha = 1, 2$ ) can be written as

$$I_1(r) = \frac{V_1(r) - V_2(r)}{R_1} + \frac{V_1(r) - V_2(r-a)}{R_2},$$

$$I_2(r) = \frac{V_2(r) - V_1(r)}{R_1} + \frac{V_2(r) - V_1(r+a)}{R_2}.$$

Hence, the Laplacian matrix can be written as

$$\mathbf{L}(r) = \begin{bmatrix} -\frac{\delta_{r,0}}{R_1} - \frac{\delta_{r,0}}{R_2} & \frac{\delta_{r,0}}{R_1} + \frac{\delta_{r,a}}{R_2} \\ \frac{\delta_{r,0}}{R_1} + \frac{\delta_{r,-a}}{R_2} & -\frac{\delta_{r,0}}{R_1} - \frac{\delta_{r,0}}{R_2} \end{bmatrix}, \quad (15a)$$

and its Fourier transformation reads

$$\mathbf{L}(k) = \begin{bmatrix} -\frac{1}{R_1} - \frac{1}{R_2} & \frac{1}{R_1} + \frac{e^{-ika}}{R_2} \\ \frac{1}{R_1} + \frac{e^{ika}}{R_2} & -\frac{1}{R_1} - \frac{1}{R_2} \end{bmatrix}. \quad (15b)$$

Inverting the matrix  $\mathbf{L}(k)$  the Green's function defined by Eq. (5b) becomes

$$\mathbf{G}(k) = \frac{1}{4 \sin^2 \frac{ka}{2}} \begin{bmatrix} R_1 + R_2 & R_2 + R_1 e^{-ika} \\ R_2 + R_1 e^{-ika} & R_1 + R_2 \end{bmatrix}. \quad (16)$$

Now, changing the variable  $k$  to  $x$ , the Green's function in Eq. (13) (for  $d = 1$ ) transforms to  $G(x) = G(ka \rightarrow x)$ .

The resistance between lattice point  $\{0, \alpha\}$  and  $\{ma, \beta\}$  can be obtained from Eq. (13) for one dimensional case ( $d = 1$ ):

$$R_{11}(m) = R_{22}(m) = (R_1 + R_2) f(m), \quad (17a)$$

$$R_{12}(m) = R_1 f(m+1) + R_2 f(m), \quad (17b)$$

$$R_{21}(m) = R_1 f(m-1) + R_2 f(m), \quad \text{where} \quad (17c)$$

$$f(m) = \int_{-\pi}^{\pi} \frac{dx}{2\pi} \frac{1 - \cos mx}{1 - \cos x}. \quad (17d)$$

The function  $f(m)$  can be evaluated using the method of residues and we find  $f(m) = |m|$ , if  $m$  is an integer. Thus,  $R_{11}(m) = (R_1 + R_2) |m|$ ,  $R_{12}(m) = R_1 |m+1| + R_2 |m|$  and  $R_{21}(m) = R_1 |m-1| + R_2 |m|$ . These results can easily be understood from the fact that the current flows only between lattice point  $\{0, \alpha\}$  and  $\{ma, \beta\}$ , and between these points the resistances are in series. The two semi-infinite segments of the chain do not affect the resistance.

#### B. Tiling of the plane by squares and octagons

Consider the resistor network shown in Fig. 1. Hereafter, we assume that all lines represent a resistor with resistance  $R$ . Using the Ohm's and Kirchoff's laws the currents  $I_\alpha(\mathbf{r})$  at site  $\{\mathbf{r}, \alpha\}$  (with  $\alpha = 1, 2, 3, 4$ ) can be written as

$$I_1(\mathbf{r}) = \frac{V_1(\mathbf{r}) - V_2(\mathbf{r})}{R} + \frac{V_1(\mathbf{r}) - V_3(\mathbf{r} - \mathbf{a}_1)}{R} + \frac{V_1(\mathbf{r}) - V_4(\mathbf{r})}{R}, \quad (18a)$$

$$I_2(\mathbf{r}) = \frac{V_2(\mathbf{r}) - V_1(\mathbf{r})}{R} + \frac{V_2(\mathbf{r}) - V_3(\mathbf{r})}{R} + \frac{V_2(\mathbf{r}) - V_4(\mathbf{r} - \mathbf{a}_2)}{R}, \quad (18b)$$

$$I_3(\mathbf{r}) = \frac{V_3(\mathbf{r}) - V_1(\mathbf{r} + \mathbf{a}_1)}{R} + \frac{V_3(\mathbf{r}) - V_2(\mathbf{r})}{R} + \frac{V_3(\mathbf{r}) - V_4(\mathbf{r})}{R}, \quad (18c)$$

$$I_4(\mathbf{r}) = \frac{V_4(\mathbf{r}) - V_1(\mathbf{r})}{R} + \frac{V_4(\mathbf{r}) - V_2(\mathbf{r} + \mathbf{a}_2)}{R} + \frac{V_4(\mathbf{r}) - V_3(\mathbf{r})}{R}. \quad (18d)$$

From these equations one can easily read out the Laplacian matrix:

$$\mathbf{L}(\mathbf{r}) = \frac{1}{R} \begin{bmatrix} -3\delta_{\mathbf{r},0} & \delta_{\mathbf{r},0} & \delta_{\mathbf{r},\mathbf{a}_1} & \delta_{\mathbf{r},0} \\ \delta_{\mathbf{r},0} & -3\delta_{\mathbf{r},0} & \delta_{\mathbf{r},0} & \delta_{\mathbf{r},\mathbf{a}_2} \\ \delta_{\mathbf{r},-\mathbf{a}_1} & \delta_{\mathbf{r},0} & -3\delta_{\mathbf{r},0} & \delta_{\mathbf{r},0} \\ \delta_{\mathbf{r},0} & \delta_{\mathbf{r},-\mathbf{a}_2} & \delta_{\mathbf{r},0} & -3\delta_{\mathbf{r},0} \end{bmatrix}. \quad (19)$$

Hence, the Fourier transform of the Laplacian matrix (19) is given by

$$\mathbf{L}(\mathbf{k}) = \frac{1}{R} \begin{bmatrix} -3 & 1 & e^{-i\mathbf{k}\mathbf{a}_1} & 1 \\ 1 & -3 & 1 & e^{-i\mathbf{k}\mathbf{a}_2} \\ e^{i\mathbf{k}\mathbf{a}_1} & 1 & -3 & 1 \\ 1 & e^{i\mathbf{k}\mathbf{a}_2} & 1 & -3 \end{bmatrix}. \quad (20)$$

Inverting the above matrix  $\mathbf{L}(\mathbf{k})$  the Green's function can easily be calculated from Eq. (5b) and changing the variables we find

$$\mathbf{G}(x_1, x_2) = \mathbf{G}(\mathbf{k}\mathbf{a}_1 \rightarrow x_1, \mathbf{k}\mathbf{a}_2 \rightarrow x_2). \quad (21)$$

Since the resistance depends only on the difference  $\mathbf{r}_2 - \mathbf{r}_1$  we can take the lattice vector  $\mathbf{r}_1$  (at which the current  $I$  enters the network) to the origin. Specify the lattice vector  $\mathbf{r}_2 \equiv \mathbf{r}_0 = m\mathbf{a}_1 + n\mathbf{a}_2$  (at which the current  $I$  exits the network). Then using the main result (13) for  $d = 2$ , the resistance between lattice point  $\{\mathbf{0}, \alpha\}$  and  $\{\mathbf{r}_0, \beta\}$  is given by

$$\begin{aligned} R_{\alpha\beta}(m, n) &= \int_{-\pi}^{\pi} \frac{dx_1}{2\pi} \int_{-\pi}^{\pi} \frac{dx_2}{2\pi} \left[ G_{\alpha\alpha}(x_1, x_2) \right. \\ &+ G_{\beta\beta}(x_1, x_2) - G_{\alpha\beta}(x_1, x_2) e^{-i(m x_1 + n x_2)} \\ &\left. - G_{\beta\alpha}(x_1, x_2) e^{i(m x_1 + n x_2)} \right]. \end{aligned} \quad (22)$$

It can be shown that in the above expression one integral can be evaluated analytically by the method of residues[28] much in the same way as in Ref. [5] for square and triangular lattices.

Applying this result we calculated the resistance for a few cases. For example, the resistance between lattice point 1 and 2 that belong to the same unit cell, we obtain

$$\begin{aligned} R_{12}(0, 0) &= \frac{R}{2} \int_{-\pi}^{\pi} \frac{dx_1}{2\pi} \int_{-\pi}^{\pi} \frac{dx_2}{2\pi} f(x_1, x_2), \\ f(x_1, x_2) &= \frac{-9 + 4 \cos x_1 + 4 \cos x_2 + \cos(x_1 - x_2)}{-7 + 3 \cos x_1 + 3 \cos x_2 + \cos x_1 \cos x_2}. \end{aligned} \quad (23a)$$

Performing the integrations we find

$$R_{12}(0, 0) = \left( \frac{1}{2} + \frac{\sqrt{2} \arctan(2\sqrt{2})}{4\pi} \right) R, \quad (23b)$$

and numerically,  $R_{12}(0, 0) \approx 0.6385R$ .

Similarly, the resistance between lattice point 1 and 3 (when they are in the same unit cell):

$$R_{13}(0, 0) = \frac{3\sqrt{2}}{2} \left( 1 - \frac{2 \arctan \sqrt{2}}{\pi} \right) R \approx 0.8312R. \quad (23c)$$

Owing to the symmetry of the lattice,  $R_{14}(0, 0) = R_{23}(0, 0) = R_{34}(0, 0) = R_{12}(0, 0)$ , and  $R_{24}(0, 0) = R_{13}(0, 0)$ .

In adjacent unit cells the two squares are connected by one resistor, and then one can ask what is the resistance between

the two ends of this resistor. In our notation, this can be found by calculating, eg,  $R_{31}(1, 0)$ . Using Eq. (22) we obtain

$$R_{31}(1, 0) = \left( 1 - \frac{\sqrt{2}}{2} + \frac{\sqrt{2} \arctan \sqrt{2}}{\pi} \right) R, \quad (23d)$$

and numerically,  $R_{31}(1, 0) \approx 0.7229R$ . For more examples, it is useful to apply the method of residues.

### C. The Kagomé lattice

The next example we consider is the so-called Kagomé lattice structure [25] shown in Fig. 4. The unit cell of the

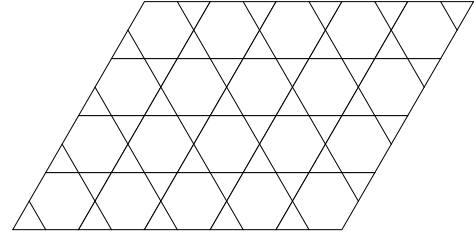


FIG. 4. The Kagomé lattice structure of the resistor network.

Kagomé lattice structure is shown in Fig. 5. Each unit cell contains three lattice points, ie,  $\alpha = 1, 2, 3$  and the Laplacian matrix is a three by three matrix. In a similar way as in

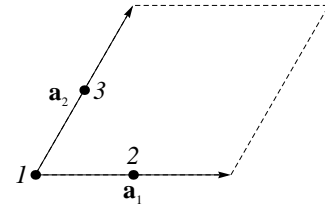


FIG. 5. The unit cell of the Kagomé lattice with three lattice points,  $p = 3$ .

Sec. III B, one can write down the equations for the currents for each lattice point in one unit cell. Then it is easy to show that the Fourier transform of the Laplacian matrix for Kagomé lattice is

$$\mathbf{L}(\mathbf{k}) = \frac{1}{R} \begin{bmatrix} -4 & 1 + e^{-i\mathbf{k}\mathbf{a}_1} & 1 + e^{-i\mathbf{k}\mathbf{a}_2} \\ 1 + e^{i\mathbf{k}\mathbf{a}_1} & -4 & 1 + e^{i\mathbf{k}(\mathbf{a}_1 - \mathbf{a}_2)} \\ 1 + e^{i\mathbf{k}\mathbf{a}_2} & 1 + e^{-i\mathbf{k}(\mathbf{a}_1 - \mathbf{a}_2)} & -4 \end{bmatrix}. \quad (24)$$

As we mentioned before Eq. (12) the lattice can be deformed to a topologically equivalent one for which the unit cell is a hypercube, in this case, it is a square lattice (see Fig. 6). Now, calculating the Green's function from Eq. (5b) and changing variables according to Eq. (21) one can use the general expression (22) to find the resistance between arbitrary lattice points on Kagomé lattice of resistor network.

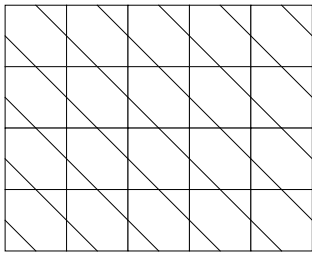


FIG. 6. The topologically equivalent lattice structure of the Kagomé lattice. The unit cell is a square.

It is interesting to calculate the resistance between adjacent lattice points. From symmetry it follows that  $R_{12}(0,0) = R_{13}(0,0) = R_{23}(0,0)$ , and from Eq. (22) we find that the integrand of the sum of these resistances is a constant and equals to  $3R/2$ . Therefore, in Eq. (22) the double integral results in  $R_{12}(0,0) + R_{13}(0,0) + R_{23}(0,0) = 3R/2$  and the resistance between the nearest neighbor lattice points is  $R_{12}(0,0) = R_{13}(0,0) = R_{23}(0,0) = R/2$ . Based on the superposition principle and the symmetry of the lattice structure the same result was found in Refs. [29, 30].

However, our general formalism enables us to find the resistance between arbitrary lattice points. Moreover, we show that the resistance  $R_{\alpha\beta}(m,n)$  on Kagomé lattice can be expressed in terms of the resistances  $R^\Delta(m,n)$  on a triangular lattice. To this end, we recall the result for triangular lattice as discussed in Refs. [4, 5]. The resistance between lattice point  $\{\mathbf{0}, 1\}$  and  $\{\mathbf{r}_0, 1\}$  (here  $\mathbf{r}_0 = m\mathbf{a}_1 + n\mathbf{a}_2$  and for triangular lattice there is only one lattice point in each unit cell which is labeled here by 1) is given by

$$R^\Delta(m,n) = R \int_{-\pi}^{\pi} \frac{dx_1}{2\pi} \int_{-\pi}^{\pi} \frac{dx_2}{2\pi} f_{mn}^\Delta(x_1, x_2), \quad \text{where}$$

$$f_{mn}^\Delta(x_1, x_2) = \frac{1 - \cos(mx_1 + nx_2)}{3 - \cos x_1 - \cos x_2 - \cos(x_1 - x_2)}. \quad (25)$$

The resistor problem for triangular lattice has been well studied in Refs. [4, 5] including a few analytical results. Note that the above expression is slightly different from that in Ref. [5] since here the angle between the two unit cell vector  $\mathbf{a}_1$  and  $\mathbf{a}_2$  is  $60^\circ$ , while in Ref. [5] it is  $120^\circ$ , but this different choice of the unit cell is irrelevant for the resistances. Now, starting from Eq. (22) one can show that the resistance  $R_{\alpha\beta}(m,n)$  on Kagomé lattice can be expressed in terms of the resistances  $R^\Delta(m,n)$  on the triangular lattice. The explicit expressions are given in Appendix A. Similar mapping of the honeycomb lattice to the triangular lattice has been demonstrated in Ref. [5]. Mathematically, such an interesting map between the Kagomé and the triangular lattice of resistor network is based on the fact that the determinant of the Laplacian for Kagomé lattice differs from the denominator of the function  $f_{mn}^\Delta(x_1, x_2)$  only by a constant factor. This mathematical fact should have a topological origin, which can be a further research topic in the future.

Using these results (see Appendix A) it is easy to find the resistance between the opposite corners of a hexagon on

Kagomé lattice, eg, by calculating  $R_{33}(1,0)$  or  $R_{22}(0,1)$  and we obtain  $R_{33}(1,0) = R_{22}(0,1) = \left(\frac{4}{9} + \frac{2\sqrt{3}}{3\pi}\right) R \approx 0.8120R$ .

#### D. The diced lattice

The diced lattice (Fig. 7) is a periodic tiling of the plane by rhombi having  $60^\circ$  and  $120^\circ$  interior angles and all vertices have degree 3 or 6. The dice lattice is a frequently used lattice structure in the literature. Recently antiferromagnetic behavior has been studied on diced lattice [31]. One possi-

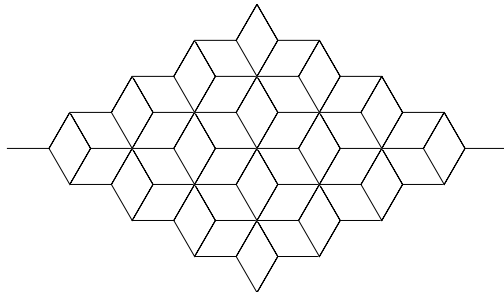


FIG. 7. The diced lattice structure.

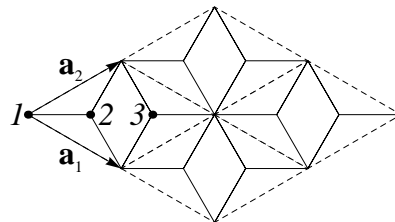


FIG. 8. The unit cell of the diced lattice with three lattice points,  $p = 3$ .

ble choice of the unit cell is shown in Fig. 8, it contains three lattice points. The diced lattice can be deformed to a topologically equivalent, two dimensional square lattice as shown in Fig. 9.

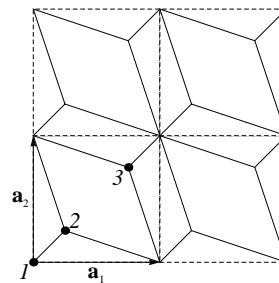


FIG. 9. The lattice structure that is topologically equivalent to the diced lattice structure.

Using the method outlined previously one can easily obtain

the Fourier transform of the Laplacian matrix for diced lattice and it is given by

$$\mathbf{L}(\mathbf{k}) = \frac{1}{R} \begin{bmatrix} -6 & A^* & B^* \\ A & -3 & 0 \\ B & 0 & -3 \end{bmatrix}, \quad (26)$$

where  $A = 1 + e^{i\mathbf{k}\mathbf{a}_1} + e^{i\mathbf{k}\mathbf{a}_2}$  and  $B = e^{i\mathbf{k}\mathbf{a}_1} + e^{i\mathbf{k}\mathbf{a}_2} + e^{i\mathbf{k}(\mathbf{a}_1 + \mathbf{a}_2)}$ .

Now, one can again use Eq. (22) to calculate the resistance between arbitrary lattice points on a diced lattice. Much in the same way as in the case of Kagomé lattice from Eq. (22) we find that the resistance between arbitrary lattice points on a diced lattice can again be expressed in terms of the corresponding resistance on triangular lattice. The explicit expressions are given in Appendix B. The mathematical reason of this mapping is the same as in the case of Kagomé lattice mentioned in Sec. III C.

Here we present a few analytical results. For instance, the resistance between lattice point 1 and 2 (which are in the same unit cell) may be found by calculating  $R_{12}(0, 0)$  and we obtain a simple result  $R_{12}(0, 0) = R/2$ . Moreover, the resistance between the two ends of the shorter and longer diagonal of a rhombus on a diced lattice may be obtained by calculating  $R_{23}(0, 0)$  and  $R_{11}(1, 0)$ , respectively and we find  $R_{23}(0, 0) = \left(\frac{5}{9} + \frac{\sqrt{3}}{3\pi}\right) R \approx 0.7393R$  and  $R_{11}(1, 0) = R/2$ .

### E. The decorated lattice

Here we consider the so-called decorated which is a square lattice with extra lattice points in the middle of each bond as shown in Fig. 10 together with a natural choice for the unit cell vectors and lattice points labeled by  $\alpha = 1, 2, 3$  in each unit cell. This lattice was used to study, eg, the phase diagram of a decorated Ising system [32] and recently the Hubbard model [33].

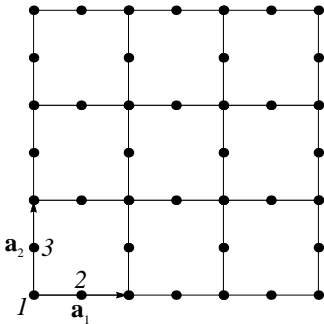


FIG. 10. The decorated lattice structure. Between each full circles the bond represents a resistor with resistance  $R$ . The unit cell contains three lattice points labeled by  $\alpha = 1, 2, 3$ , ie,  $p = 3$ .

Much in the same way as in our earlier examples one can easily find the Fourier transform of the Laplacian matrix for

decorated lattice:

$$\mathbf{L}(\mathbf{k}) = \frac{1}{R} \begin{bmatrix} -4 & 1 + e^{-i\mathbf{k}\mathbf{a}_1} & 1 + e^{-i\mathbf{k}\mathbf{a}_2} \\ 1 + e^{i\mathbf{k}\mathbf{a}_1} & -2 & 0 \\ 1 + e^{i\mathbf{k}\mathbf{a}_2} & 0 & -2 \end{bmatrix}. \quad (27)$$

Then, the resistance between arbitrary lattice points can be obtained from Eq. (22). However, again just like in the case of Kagomé and diced lattice here there is a close relation between the decorated and the square lattice regarding the resistances. We derived explicit expressions (see Appendix C) for the resistance  $R_{\alpha\beta}(m, n)$  on a decorated lattice in terms of the resistances  $R^\square(m, n)$  (between the origin and the lattice point  $m\mathbf{a}_1 + n\mathbf{a}_2$  on a square lattice) given by

$$R^\square(m, n) = R \int_{-\pi}^{\pi} \frac{dx_1}{2\pi} \int_{-\pi}^{\pi} \frac{dx_2}{2\pi} f_{mn}^\square(x_1, x_2), \quad \text{where} \\ f_{mn}^\square(x_1, x_2) = \frac{1 - \cos(mx_1 + nx_2)}{2 - \cos x_1 - \cos x_2}. \quad (28)$$

Regarding the resistor problem on square lattice see, eg, Refs. [4, 5] in which a few analytical results [4] and recurrence formulas [5] are presented. The mathematical reason of the mapping of the decorated lattice to the square lattice of resistor network is the same as in the case of Kagomé lattice mentioned in Sec. III C.

Note that the first equation in Appendix C can easily be understood with a simple argument. To find the resistance  $R_{11}(m, n)$  one can disregard the middle points of each bond on the decorated lattice. Then the decorated lattice is equivalent to a square lattice in which the bonds have resistance  $2R$ . Thus we find that  $R_{11}(m, n) = 2R^\square(m, n)$  in agreement with that given by Eq. (C1a). For example,  $R_{11}(1, 1) = 4R/\pi$ .

Using the results given in Appendix C, we find that the resistance between lattice point 1 and 2 that belong to the same unit cell is  $R_{12}(0, 0) = 3R/4$ . Similarly, the resistance between lattice point 2 and 3 (which are in the same unit cell) is  $R_{23}(0, 0) = (1 + 1/\pi) R \approx 1.3183R$ .

### F. Centered square lattice

In Secs. III C and III D we showed that the Kagomé and the diced lattice can be mapped to the triangular lattice, while in Sec. III E it was shown that the decorated lattice is mapped to the square lattice. In this section we show another interesting mapping. In particular, we find that the resistor network discussed in Sec. III B (see Fig. 1) can be mapped to the so-called centered square lattice shown in Fig. 11.

Using the Ohm's and Kirchhoff's laws we find easily that the Fourier transform of the Laplacian is

$$\mathbf{L}(\mathbf{k}) = \frac{1}{R} \begin{bmatrix} A & B^* \\ B & -4 \end{bmatrix}, \quad \text{where} \quad (29a)$$

$$A = -8 + 2(\cos \mathbf{k}\mathbf{a}_1 + \cos \mathbf{k}\mathbf{a}_2), \quad (29b)$$

$$B = (1 + e^{i\mathbf{k}\mathbf{a}_1})(1 + e^{i\mathbf{k}\mathbf{a}_2}). \quad (29c)$$

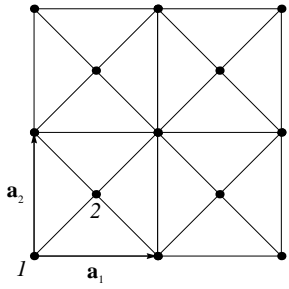


FIG. 11. The centered square lattice structure. Between each full circles the bond represents a resistor with resistance  $R$ . The unit cell contains two lattice points labeled by  $\alpha = 1, 2$ , ie,  $p = 2$ .

Then, the Green's function from Eq. (5b) becomes

$$\mathbf{G}(\mathbf{k}) = \frac{1}{\det(\mathbf{L})} \begin{bmatrix} 4 & B^* \\ B & -A \end{bmatrix}, \quad (30)$$

where the determinant of  $\mathbf{L}(\mathbf{k})$  is given by

$$R \det(\mathbf{L}) = 28 - 12(\cos \mathbf{k}\mathbf{a}_1 + \cos \mathbf{k}\mathbf{a}_2) - 4 \cos \mathbf{k}\mathbf{a}_1 \cos \mathbf{k}\mathbf{a}_2. \quad (31)$$

Note that this determinant is exactly the same as that of the Laplacian in Eq. (20). Therefore, the Green's function should have the same denominator in both cases. The numerator of the Green's functions in the two cases are different. However, the structure of the numerator of the Green's function for  $\mathbf{L}(\mathbf{k})$  given in (20) is the same as that for the centered square lattice. Thus, one can work out the resistance formulas (not presented here) analogous to that listed in the Appendices to find the explicit mapping between the lattice structure shown in Figs. 1 and 11.

Using Eq. (22) we calculated the resistance analytically for a few cases:

$$R_{11}(1, 0) = \frac{\sqrt{2} \arctan(\sqrt{2}/2)}{\pi} R, \quad (32a)$$

$$R_{12}(0, 0) = \left[ \frac{1}{2} - \frac{\sqrt{2}}{4\pi} \arctan(2\sqrt{2}) \right] R, \quad (32b)$$

$$R_{22}(1, 0) = \left[ -1 + \frac{1}{\pi} + \frac{9\sqrt{2}}{4\pi} \arctan(2\sqrt{2}) \right] R, \quad (32c)$$

and numerically,  $R_{11}(1, 0) \approx 0.2771R$ ,  $R_{12}(0, 0) \approx 0.3615R$  and  $R_{22}(1, 0) \approx 0.5651R$ .

### G. Tiling of the plane by squares and triangulares

To demonstrate how efficient our general formalism is for calculating the resistance in a resistor network, we present results for a more complex lattice. Consider a network which is a periodic tiling of the plane by squares and triangulares shown in Fig. 12. The unit cell may be chosen as can be seen in Fig. 13.

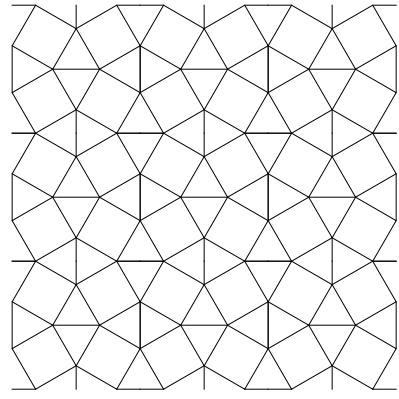


FIG. 12. The lattice is a periodic tiling of the plane by squares and triangulares.

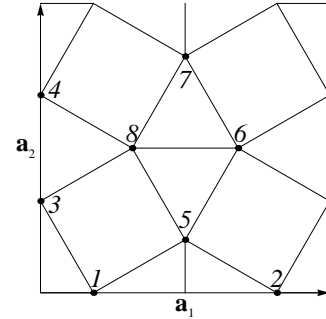


FIG. 13. The unit cell of the lattice structure shown in Fig. 12. There are eight lattice points in each unit cell,  $p = 8$ .

The Fourier transform of the Laplacian matrix for the lattice shown in Fig. 12 can easily be found:

$$\mathbf{L}(\mathbf{k}) = \frac{1}{R} \begin{bmatrix} -5 & A^* & 1 & B^* & 1 & 0 & B^* & 0 \\ A & -5 & A & C^* & 1 & 0 & B^* & 0 \\ 1 & A^* & -5 & 1 & 0 & A^* & 0 & 1 \\ B & C & 1 & -5 & 0 & A^* & 0 & 1 \\ 1 & 1 & 0 & 0 & -5 & 1 & B^* & 1 \\ 0 & 0 & A & A & 1 & -5 & 1 & 1 \\ B & B & 0 & 0 & B & 1 & -5 & 1 \\ 0 & 0 & 1 & 1 & 1 & 1 & 1 & -5 \end{bmatrix}, \quad (33)$$

where  $A = e^{i\mathbf{k}\mathbf{a}_1}$ ,  $B = e^{i\mathbf{k}\mathbf{a}_2}$  and  $C = e^{i\mathbf{k}(\mathbf{a}_2 - \mathbf{a}_1)}$ .

It is difficult to find analytical result since the integrand in Eq. (22) is a very complicated function of its variables. However, numerically we calculated the resistance  $R_{\alpha\beta}(0, 0)$  (in units of  $R$ ) between lattice points  $\alpha = 1, \dots, 8$  and



$\beta = 1, \dots, 8$  that belong to the same unit cell and find

$$R_{\alpha\beta}(0,0) = \begin{bmatrix} 0 & r_4 & r_2 & r_5 & r_2 & r_6 & r_7 & r_3 \\ r_4 & 0 & r_7 & r_8 & r_2 & r_3 & r_7 & r_6 \\ r_2 & r_7 & 0 & r_1 & r_3 & r_5 & r_6 & r_2 \\ r_5 & r_8 & r_1 & 0 & r_6 & r_5 & r_3 & r_2 \\ r_2 & r_2 & r_3 & r_6 & 0 & r_2 & r_4 & r_2 \\ r_6 & r_3 & r_5 & r_5 & r_2 & 0 & r_2 & r_1 \\ r_7 & r_7 & r_6 & r_3 & r_4 & r_2 & 0 & r_2 \\ r_3 & r_6 & r_2 & r_2 & r_2 & r_1 & r_2 & 0 \end{bmatrix}, \quad (34)$$

where  $r_1 \approx 0.3849$ ,  $r_2 \approx 0.4038$ ,  $r_3 \approx 0.5108$ ,  $r_4 \approx 0.5396$ ,  $r_5 \approx 0.5585$ ,  $r_6 \approx 0.5647$ ,  $r_7 \approx 0.6230$ ,  $r_8 \approx 0.6631$ . It is interesting to note that the resistance  $R_{14} = r_5$  and  $R_{16} = r_6$  numerically are almost the same. However, rigorously they are not the same since they are not related to each other by symmetry.

### H. Body centered cubic lattice

Finally, we present a non-trivial example for a three dimensional lattice of resistor network. The simplest cubic lattice has already been studied in Ref. [5]. Consider a more complicated resistor network, namely the body centered cubic (bcc) lattice shown in Fig. 14.

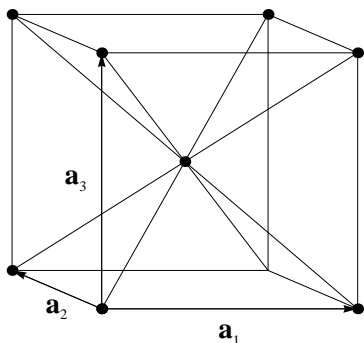


FIG. 14. The body centered cubic lattice as a periodic tiling of the three dimensional space. Besides the sides of the cube there are resistors between the center of the cube and its corners. There are two non-equivalent lattice points in the bcc lattice, one is at one of the corner of the cube and the other is at the center of the cube, i.e.,  $p = 2$ . The unit cell vectors are  $\mathbf{a}_1$ ,  $\mathbf{a}_2$  and  $\mathbf{a}_3$ . All lines represent a resistor with resistance  $R$ .

As we demonstrated above, the Laplacian matrix can be obtained from the Ohm's and Kirchoff's laws and we find that its Fourier transformation can be written as

$$\mathbf{L}(\mathbf{k}) = \frac{1}{R} \begin{bmatrix} A - 14 & B^* \\ B & -8 \end{bmatrix}, \quad \text{where} \quad (35a)$$

$$A = 2(\cos \mathbf{k}\mathbf{a}_1 + \cos \mathbf{k}\mathbf{a}_2 + \cos \mathbf{k}\mathbf{a}_3), \quad (35b)$$

$$B = (1 + e^{i\mathbf{k}\mathbf{a}_1})(1 + e^{i\mathbf{k}\mathbf{a}_2})(1 + e^{i\mathbf{k}\mathbf{a}_3}). \quad (35c)$$

Then, the Green's function from Eq. (5b) becomes

$$\mathbf{G}(\mathbf{k}) = \frac{1}{\det(\mathbf{L})} \begin{bmatrix} 8 & B^* \\ B & 14 - A \end{bmatrix}, \quad (36)$$

where the determinant of  $\mathbf{L}(\mathbf{k})$  is given by

$$R \det(\mathbf{L}) = 112 - 16(\cos \mathbf{k}\mathbf{a}_1 + \cos \mathbf{k}\mathbf{a}_2 + \cos \mathbf{k}\mathbf{a}_3) - 8(1 + \cos \mathbf{k}\mathbf{a}_1)(1 + \cos \mathbf{k}\mathbf{a}_2)(1 + \cos \mathbf{k}\mathbf{a}_3). \quad (37)$$

The resistance between two arbitrary lattice points can be determined from Eq. (13) for  $d = 3$ . For a few cases we find numerically that the resistances (in units of  $R$ ) are  $R_{12}(0,0,0) \approx 0.1945$ ,  $R_{11}(1,0,0) \approx 0.1481$ ,  $R_{11}(1,1,0) \approx 0.1651$ ,  $R_{11}(1,1,1) \approx 0.1717$  and  $R_{22}(1,0,0) \approx 0.2657$ . It is interesting to note that the resistance  $R_{11}(1,0,0)$  (resistance between the two ends of a side of the cube) is much less than that in the simple cubic lattice (in this case it is  $R/3$ , see, eg, [5]). The physical reason is that comparing with the simple cubic lattice, the body centered cubic lattice provides more channels for the current flowing between the two lattice points.

### IV. CONCLUSIONS

In this work using the Green's function method we derived a general resistance formula for any infinite lattice structures of resistor networks that is a periodic tiling of space in all dimensions. Our general resistance formula was applied for several non-trivial resistor networks to demonstrate how versatile our approach is. For the Kagomé and dice lattice we derived explicit expressions for the resistances between two arbitrary lattice points in terms of the resistances on triangular lattice of resistors. Similarly, we show that there is a direct map between the decorated lattice and the square lattice. We pointed out that mapping between the lattice structure shown in Figs. 1 and 11 can exist. We believed that such a mapping between different lattice structures of resistor networks has a topological reason. In fact, we think there exists a classification of the different resistor networks in terms of some classes. However, to have deeper understanding of this issue more works needs to be done. This problem could be a future challenge for physicists and mathematicians.

Tiling of plane is common in arts and its mathematical description based on group theory is well known in the literature. Under the title 'tiling' one can find various and decorative examples for possible tiling on the web. Replacing the lines by resistors in such tilings provides a wealth example for possible resistor networks not studied in the literature. Here, we presented examples that are well known and relatively simple to find analytical results. However, our Green's function method is general and makes it possible to study very complicated lattice structure like that discussed in Sec. III G.

Our work can be extended to study the classical lattice dynamics and the vibrational modes of atoms within the framework of harmonic approximation. Similarly, description of the electron dynamics governed by Schrödinger equation in tight binding approximation could be another application of the Green's function approach outlined here in the example of resistor networks.

## ACKNOWLEDGMENTS

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### Appendix A: Relation between the Kagomé and the triangular lattice of resistor network

In this section we listed the results for the resistance  $R_{\alpha\beta}(m, n)$  on Kagomé lattice in terms of the resistances  $R^\Delta(m, n)$  on a triangular lattice:

$$R_{11}(m, n) = \frac{R}{9} + \frac{7}{3} R^\Delta(m, n) - \frac{1}{6} \left[ R^\Delta(m-1, n+1) + R^\Delta(m+1, n-1) \right], \quad (\text{A1a})$$

$$R_{12}(m, n) = \frac{R}{9} + \frac{5}{6} \left[ R^\Delta(m, n) + R^\Delta(m+1, n) \right] + \frac{1}{6} \left[ R^\Delta(m+1, n-1) + R^\Delta(m, n+1) \right], \quad (\text{A1b})$$

$$R_{13}(m, n) = \frac{R}{9} + \frac{5}{6} \left[ R^\Delta(m, n) + R^\Delta(m, n+1) \right] + \frac{1}{6} \left[ R^\Delta(m+1, n) + R^\Delta(m-1, n+1) \right], \quad (\text{A1c})$$

$$R_{22}(m, n) = \frac{R}{9} + \frac{7}{3} R^\Delta(m, n) - \frac{1}{6} \left[ R^\Delta(m, n-1) + R^\Delta(m, n+1) \right], \quad (\text{A1d})$$

$$R_{23}(m, n) = \frac{R}{9} + \frac{5}{6} \left[ R^\Delta(m, n) + R^\Delta(m-1, n+1) \right] + \frac{1}{6} \left[ R^\Delta(m-1, n) + R^\Delta(m, n+1) \right], \quad (\text{A1e})$$

$$R_{33}(m, n) = \frac{R}{9} + \frac{7}{3} R^\Delta(m, n) - \frac{1}{6} \left[ R^\Delta(m-1, n) + R^\Delta(m+1, n) \right]. \quad (\text{A1f})$$

The remaining resistances can be obtained from the symmetry relation  $R_{\alpha\beta}(m, n) = R_{\beta\alpha}(-m, -n)$ .

### Appendix B: Relation between the diced and the triangular lattice of resistor network

Here we listed the results for the resistance  $R_{\alpha\beta}(m, n)$  on a diced lattice in terms of the resistances  $R^\Delta(m, n)$  on a triangular lattice:

$$R_{11}(m, n) = \frac{3}{2} R^\Delta(m, n), \quad (\text{B1a})$$

$$R_{12}(m, n) = \frac{R}{6} + \frac{1}{2} \left[ R^\Delta(m, n) + R^\Delta(m+1, n) + R^\Delta(m, n+1) \right], \quad (\text{B1b})$$

$$R_{13}(m, n) = \frac{R}{6} + \frac{1}{2} \left[ R^\Delta(m+1, n) + R^\Delta(m, n+1) + R^\Delta(m+1, n+1) \right], \quad (\text{B1c})$$

$$R_{22}(m, n) = \frac{R}{3} (1 - \delta_{m0}\delta_{n0}) + \frac{3}{2} R^\Delta(m, n), \quad (\text{B1d})$$

$$R_{23}(m, n) = \frac{R}{3} + \frac{1}{6} \left[ 2R^\Delta(m, n) + 2R^\Delta(m+1, n) + 2R^\Delta(m, n+1) + R^\Delta(m-1, n+1) + R^\Delta(m+1, n-1) + R^\Delta(m+1, n+1) \right], \quad (\text{B1e})$$

$$R_{33}(m, n) = R_{22}(m, n). \quad (\text{B1f})$$

The remaining resistances can be obtained from the symmetry relation  $R_{\alpha\beta}(m, n) = R_{\beta\alpha}(-m, -n)$ .

### Appendix C: Relation between the decorated lattice and the square lattice of resistor network

Here we listed the results for the resistance  $R_{\alpha\beta}(m, n)$  on a diced lattice in terms of the resistances  $R^\square(m, n)$  on a square

lattice:

$$R_{11}(m, n) = 2 R^{\square}(m, n), \quad (\text{C1a})$$

$$R_{12}(m, n) = \frac{R}{4} + R^{\square}(m, n) + R^{\square}(m+1, n), \quad (\text{C1b})$$

$$R_{13}(m, n) = \frac{R}{4} + R^{\square}(m, n) + R^{\square}(m, n+1), \quad (\text{C1c})$$

$$R_{22}(m, n) = \frac{R}{2} + 3 R^{\square}(m, n) - \frac{1}{2} \left[ R^{\square}(m, n-1) + R^{\square}(m, n+1) \right], \quad (\text{C1d})$$

$$R_{23}(m, n) = \frac{R}{2} + \frac{1}{2} \left[ R^{\square}(m, n) + R^{\square}(m-1, n) + R^{\square}(m-1, n+1) + R^{\square}(m, n+1) \right], \quad (\text{C1e})$$

$$R_{33}(m, n) = \frac{R}{2} + 3 R^{\square}(m, n) - \frac{1}{2} \left[ R^{\square}(m-1, n) + R^{\square}(m+1, n) \right]. \quad (\text{C1f})$$

The remaining resistances can be obtained from the symmetry relation  $R_{\alpha\beta}(m, n) = R_{\beta\alpha}(-m, -n)$ .

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